

SUT041

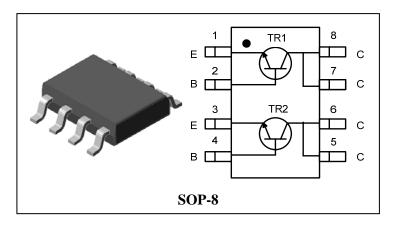
Dual NPN Bipolar transistor

Descriptions

- General purpose amplifier
- Recommended for LED Drive Application

Features

- General Purpose application
- Low saturation: $V_{CE}(sat) = 0.5V Max$
- 2 NPN chips in SOP-8 Package



Ordering Information

Type NO.	Marking	Package Code	
SUT041	SUT041□	SOP-8	

 $\hfill\Box$: Year & Week Code

Absolute maximum ratings(TR1, TR2)

	(Ta	1=25°	°C)
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Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	45	V
Collector-Emitter voltage	V_{CEO}	40	V
Emitter-Base voltage	V_{EBO}	5	V
Callagtan augusant	I_{C}	1	A(DC)
Collector current	$I_{CP} *$	2	A(Pulse)
Collector rewar discipation	D **	2	W/TOTAL
Collector power dissipation	P _C **	1.4	W/ELEMENT
Junction temperature	T _J	150	°C
Storage temperature	T_{stg}	-55~150	°C

^{*:} Single pulse, tp= 300 μ s

Electrical Characteristics(TR1, TR2)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base breakdown voltage	BV _{CBO}	$I_C=100\mu A,\ I_E=0$	45	-	-	V
Collector-Emitter breakdown voltage	BV _{CEO}	$I_C=1$ mA, $I_B=0$	40	-	-	V
Emitter-Base breakdown voltage	BV _{EBO}	$I_E=10\mu A,\ I_C=0$	5	-	-	V
Collector cut-off current	I_{CBO}	V _{CB} =45V, I _E =0	-	-	0.1	μА
Emitter cut-off current	I_{EBO}	$V_{EB}=5V$, $I_C=0$	-	-	0.1	μА
DC current gain	h _{FE} 1)	V_{CE} =1V, I_{C} =100mA	160	-	320	-
Collector-Emitter saturation voltage	V _{CE(sat)}	I _C =500mA, I _B =50mA	-	-	0.5	V
Transition frequency	f _T	V_{CE} =5V, I_{C} =10mA	-	150	-	MHz
Collector output capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz	-	8	-	pF

^{*} Note 1) hFE Rank: 160~320 only

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^{**:} When mounted on 40x40x0.8 mm copper substrate

Electrical Characteristic Curves(TR1, TR2)

Fig. 1 P_C - T_a

2500

When mounted on 40x40x0.8mm copper substrate

2000

1500

Single Rating

75

Ambient temperature Ta [°C]

100

125

150

Collector power disspation $P\sigma$ [mW]

500

0

25

50

Fig. 2 I_C - V_{BE}

1000

VCB=1V

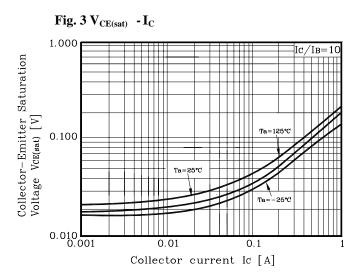
100

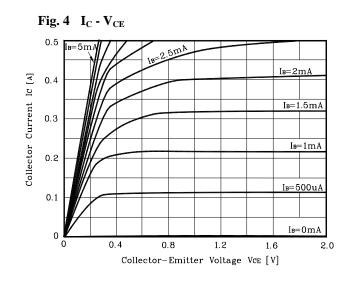
100

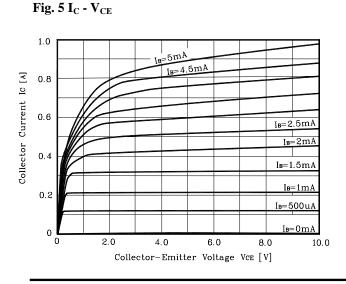
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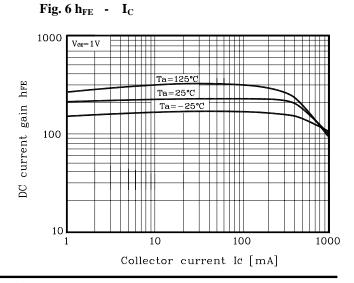
0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6

Base-Emitter voltage VBE [V]









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Fig. 7 h_{FE} - I_C

1000

Ves=2V

Ta=125°C

Ta=-25°C

Ta=-25°C

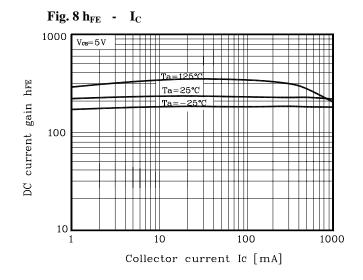
Ta=-25°C

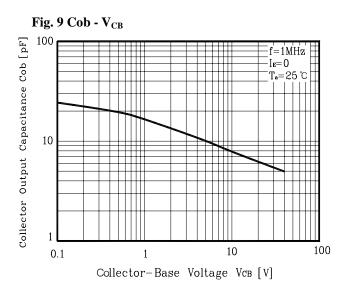
Ta=-25°C

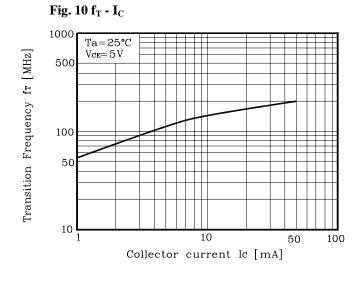
Ta=-25°C

Ta=-25°C

Collector current Ic [mA]

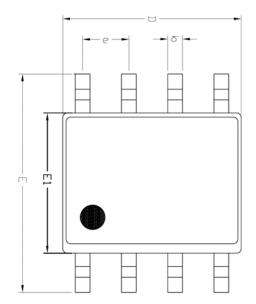


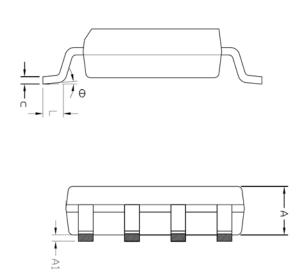




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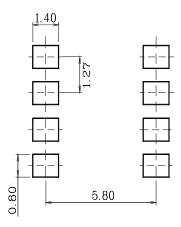
Outline Dimension





SYMBOL	MILLIMETER(mm)			NOTE
	MINIMUM	NDMINAL	MAXIMUM	I NOTE
Α	1.245	_	1.445	
A1	0.125	0.175	0.275	
b	0.320	0.420	0.520	
С	0.170	0.220	0.270	
D	4.802	4.902	5.002	
Ε	5.870	6.020	6.170	
E1	3.761	3.861	3.961	
е	1.270 BSC			
L	0.462	0.562	0.662	
θ	0 *	_	8 *	

***Recommend PCB solder land [Unit: mm]**



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